

1. General description

Hyperfast power diode in a TO247 (True 2-pin) plastic package.



AEC - Q101 Qualified



2. Features and benefits

- Low leakage current
- Low thermal resistance
- Low reverse recovery current
- Reduces switching losses in associated MOSFET or IGBT
- High operating temperature capability ($T_{j(max)} = 175^{\circ}\text{C}$)
- AEC-Q101 Qualified
- Pb-Free, Halogen Free & RoHS compliant

3. Applications

- Automotive On Board Charger
- Automotive DCDC converter
- Half-bridge/full-bridge switched-mode power supplies
- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Power Switching Circuits

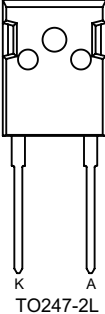
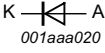
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage			600			V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 117^{\circ}\text{C}$; Fig. 1 ; Fig. 2 ; Fig. 3		30			A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25 \mu\text{s}$; $T_{mb} \leq 117^{\circ}\text{C}$; square-wave pulse		60			A
I_{FSM}	non-repetitive peak forward current	$t_p = 10 \text{ ms}$; $T_{j(init)} = 25^{\circ}\text{C}$; sine-wave pulse; Fig. 4		295			A
		$t_p = 8.3 \text{ ms}$; $T_{j(init)} = 25^{\circ}\text{C}$; sine-wave pulse		325			A
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	$I_F = 30 \text{ A}$; $T_j = 25^{\circ}\text{C}$; Fig. 6		-	1.90	2.40	V
Dynamic characteristics							
t_{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $di_F/dt = 100 \text{ A}/\mu\text{s}$; $T_j = 25^{\circ}\text{C}$; Fig. 7		-	27	-	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	mb	mounting base; connected to cathod		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYC30W-600PT2-A	TO247-2L	BYC30W-600PT2-AQ	Tube	30	TO247L-2L	10-Nov-2020

7. Marking

Table 4. Marking codes

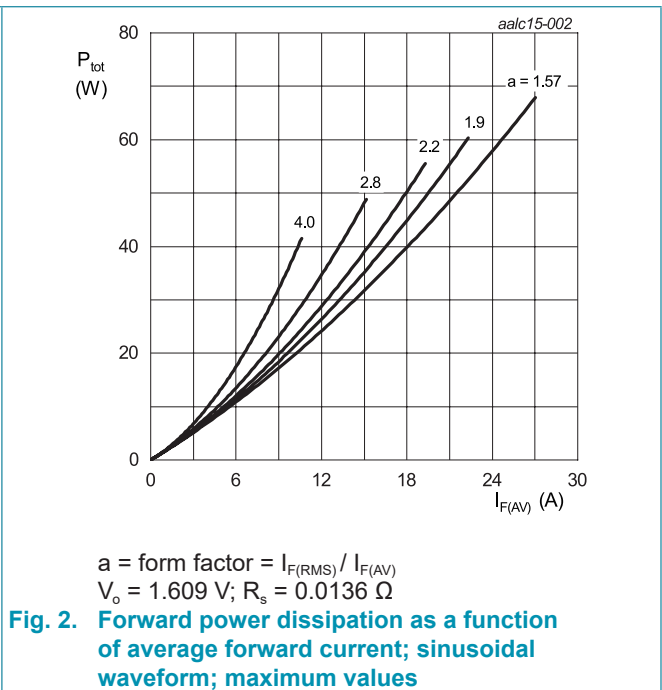
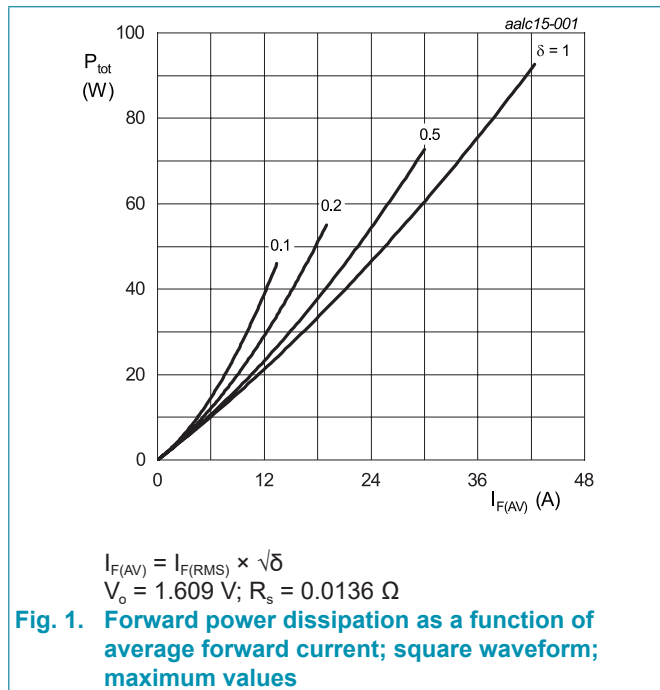
Type number	Marking codes
BYC30W-600PT2-A	BYC30W 600PT2-A

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			600	V
V_{RWM}	crest working reverse voltage			600	V
V_R	reverse voltage	DC		600	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 117\text{ }^\circ\text{C}$; Fig. 1 ; Fig. 2 ; Fig. 3		30	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 117\text{ }^\circ\text{C}$; square-wave pulse		60	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; sine-wave pulse; Fig. 4		295	A
		$t_p = 8.3\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; sine-wave pulse		325	A
T_{stg}	storage temperature			-55 to 175	$^\circ\text{C}$
T_j	junction temperature			-55 to 175	$^\circ\text{C}$



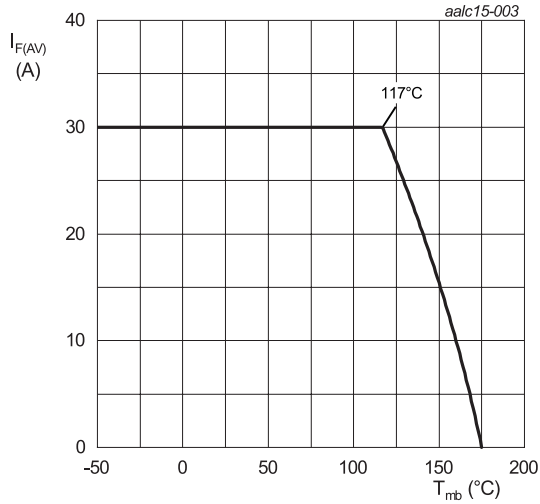


Fig. 3. Forward current as a function of mounting base temperature; maximum values

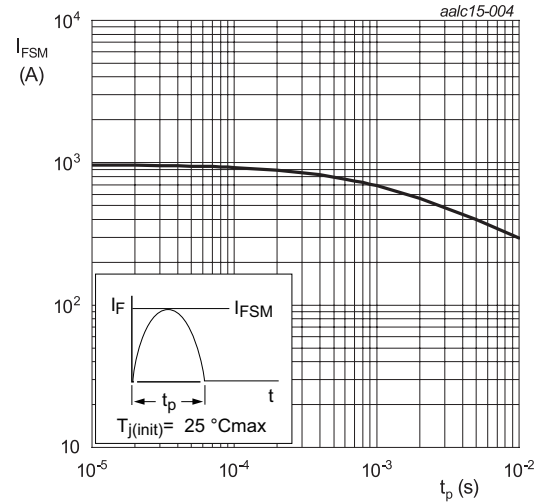


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	-	0.8	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W

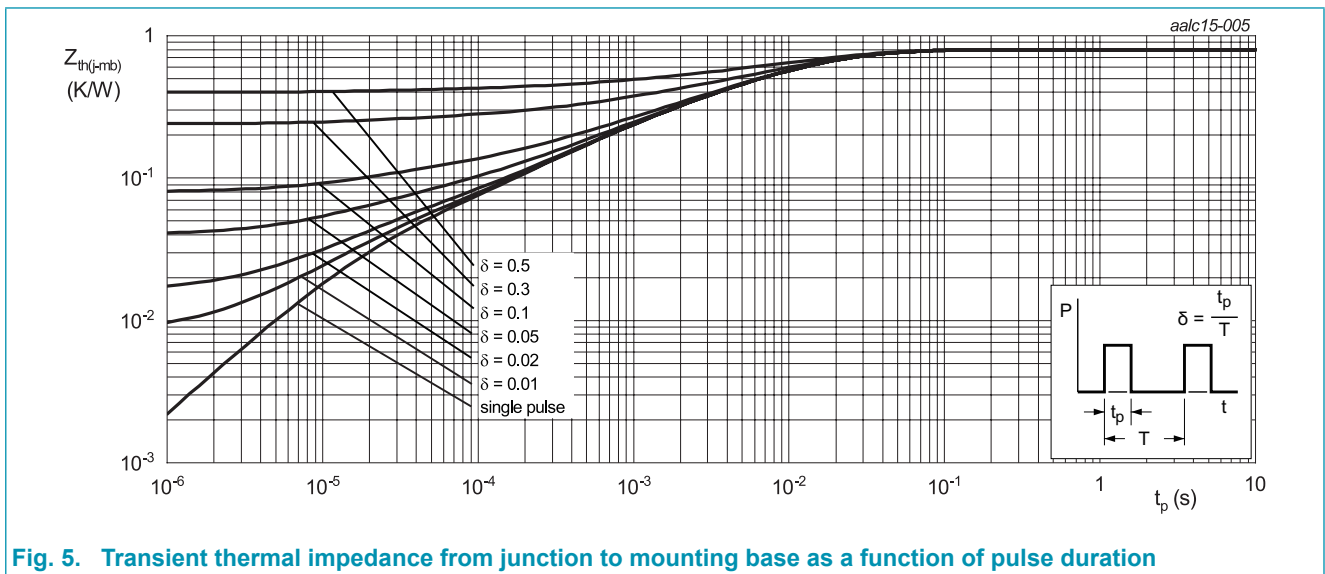
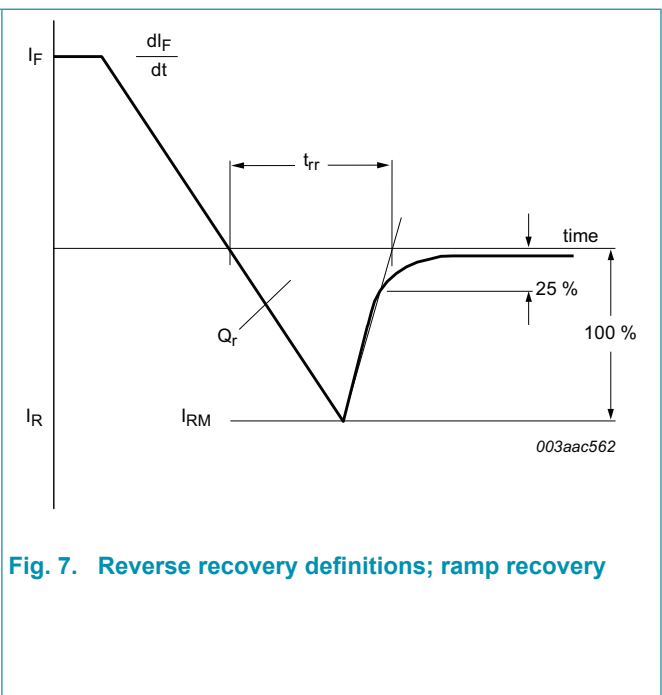
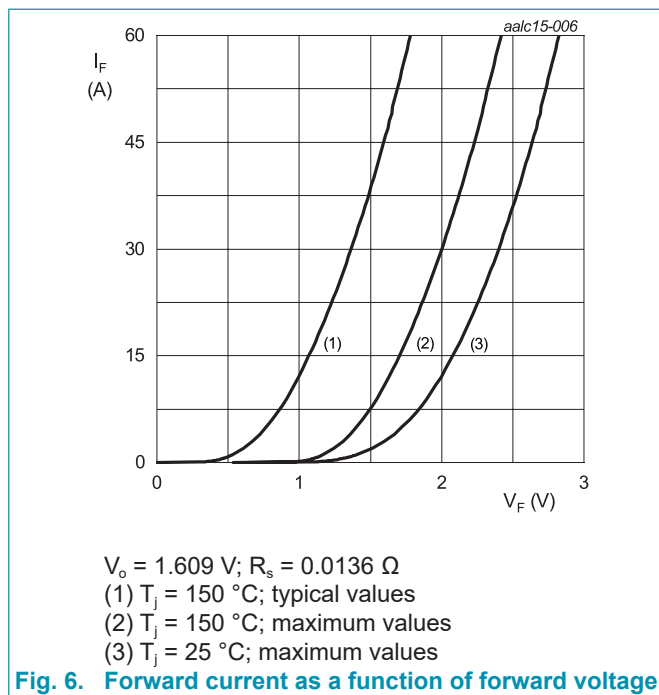


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

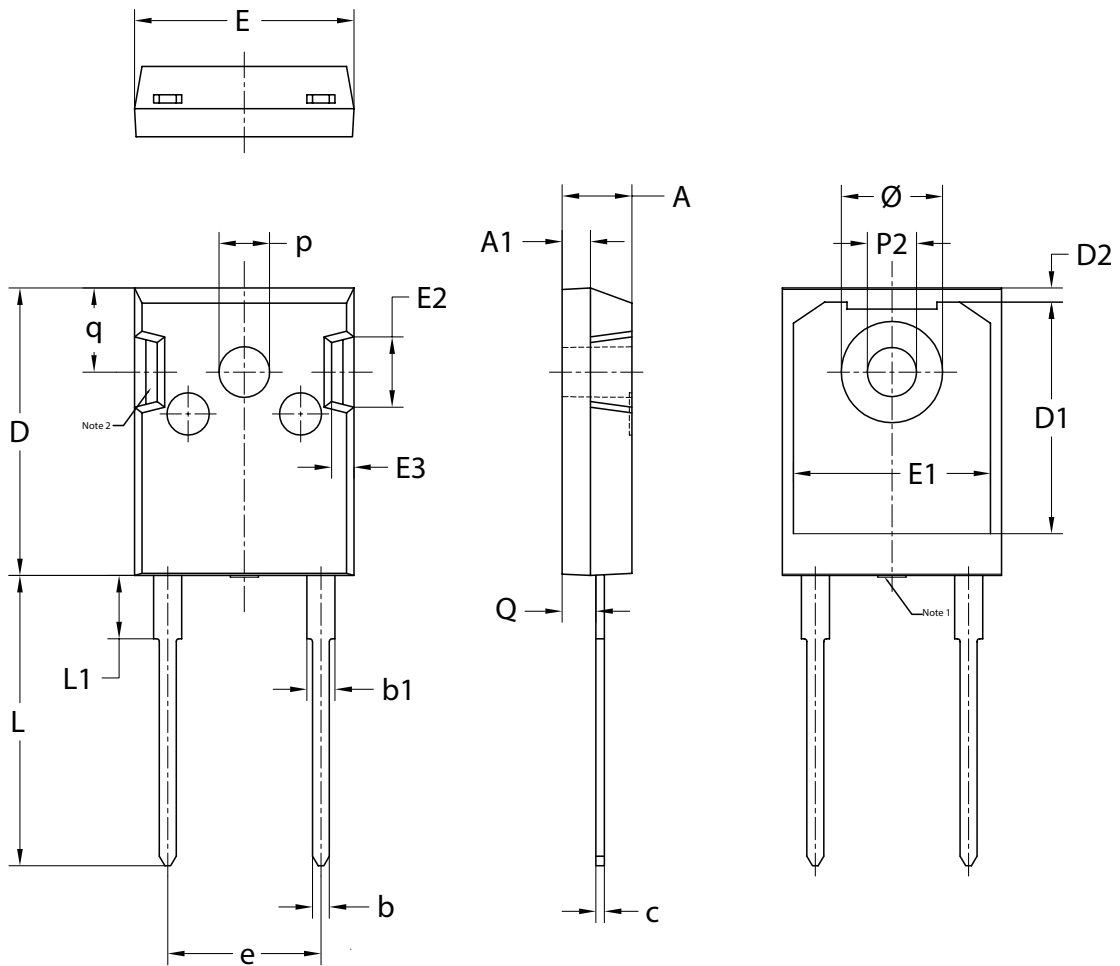
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	$I_F = 30\text{ A}; T_j = 25\text{ °C}; \text{Fig. 6}$		-	1.90	2.40	V
		$I_F = 30\text{ A}; T_j = 150\text{ °C}; \text{Fig. 6}$		-	1.40	2.00	V
I_R	reverse current	$V_R = 600\text{ V}; T_j = 25\text{ °C}$		-	-	30	μA
		$V_R = 600\text{ V}; T_j = 150\text{ °C}$		-	-	1	mA
Dynamic characteristics							
Q_r	reverse charge	$I_F = 30\text{ A}; V_R = 400\text{ V}; \text{d}I_F/\text{d}t = 200\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$		-	112	-	nC
		$I_F = 30\text{ A}; V_R = 400\text{ V}; \text{d}I_F/\text{d}t = 200\text{ A}/\mu\text{s}; T_j = 125\text{ °C}; \text{Fig. 7}$		-	470	-	nC
t_{rr}	reverse recovery time	$I_F = 1\text{ A}; V_R = 30\text{ V}; \text{d}I_F/\text{d}t = 100\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$		-	27	-	ns
		$I_F = 30\text{ A}; V_R = 400\text{ V}; \text{d}I_F/\text{d}t = 200\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$		-	60	-	ns
		$I_F = 30\text{ A}; V_R = 400\text{ V}; \text{d}I_F/\text{d}t = 200\text{ A}/\mu\text{s}; T_j = 125\text{ °C}; \text{Fig. 7}$		-	100	-	ns
I_{RM}	peak reverse recovery current	$I_F = 30\text{ A}; V_R = 400\text{ V}; \text{d}I_F/\text{d}t = 200\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$		-	3.8	-	A
		$I_F = 30\text{ A}; V_R = 400\text{ V}; \text{d}I_F/\text{d}t = 200\text{ A}/\mu\text{s}; T_j = 125\text{ °C}; \text{Fig. 7}$		-	9.4	-	A
E_{as}	non-repetitive avalanche energy	$T_{j(\text{init})} = 25\text{ °C}$		20	-	-	mJ



11. Package outline

Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 2 leads TO-247

TO247-2L



UNIT	A	A ₁	b	b ₁	c	D	D ₁ ⊕	D ₂	E	E ₁	E ₂	E ₃	e	L	L ₁	P ₂	p	Q	q	Ø
mm	5.20	2.10	1.40	2.20	0.70	20.60	16.20	1.20	15.75	14.22	5.20	1.80	10.90	20.72	4.75	3.60	3.70	2.60	6.18	7.30
	4.70	1.90	1.00	1.80	0.50	20.30	16.87	0.80	15.45	13.82	4.80	1.40	BSC	20.22	4.25	3.40	3.50	2.20	5.78	7.10

Note:

1. Mold resin protrusion max 0.127mm.
2. Metal exposed with Sn plating.

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 04 July 2022
